MG6402WZ

650V 50A Insulated Gate Bipolar Transistor

Datasheet

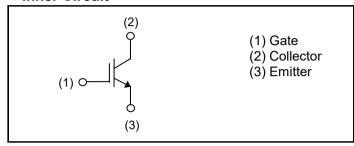
V_{CES}	650V
I _{C (Nominal)}	50A
V _{CE(sat) (Typ.)}	1.5V
Max. Possible Chips per Wafer	684pcs

•Outline Wafer

Features

- 1) Trench Light Punch Through Type
- 2) Low Collector Emitter Saturation Voltage
- 3) High Speed Switching & Low Switching Loss
- 4) Short Circuit Withstand Time 2µs

●Inner Circuit



Application

Solar Inverter

UPS

Welding

ΙH

PFC

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit		
Collector - Emitter Voltage, T _j = 25°C	V_{CES}	650	V		
Gate - Emitter Voltage	V_{GES}	±30	V		
Collector Current	I _C ^{*1}	*1)	Α		
Pulsed Collector Current	I _{CP} *2	200	Α		
Operating Junction Temperature	T _j	-40 to +175	°C		

^{*1} Depending on thermal properties of assembly

^{*2} Pulse width limited by $T_{jmax.}$

●Design Assurance

Parameter	Parameter Symbol Conditions		Values			Unit
raiailletei	Symbol	Conditions	Min.	Тур.	Max.	Offic
		$V_{CC} \le 360V$,				
Short Circuit Withstand Time	t _{sc} *3	$V_{CC} \le 360V$, $V_{GE} = 15V$, $T_i = 25^{\circ}C$	2	-	-	μs
		T _j = 25°C				
		$I_C = 200A, V_{CC} = 520V,$				
Reverse Bias Safe Operating Area	RBSOA*3	$I_C = 200A$, $V_{CC} = 520V$, $V_P = 650V$, $V_{GE} = 15V$, $R_G = 100\Omega$, $T_j = 175^{\circ}C$	FULL SQUARE		-	
,		$R_G = 100\Omega, T_j = 175^{\circ}C$				

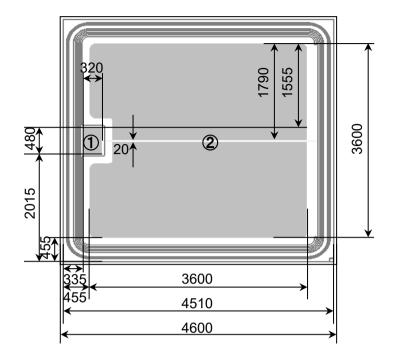
^{*3} Design assurance without measurement

●Electrical Characteristics (at T_j = 25°C unless otherwise specified, in case of TO-247N package)

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Parameter	Symbol	Conditions	Values			Unit
	- J	C 0.1.3.13	Min.	Тур.	Max.	-
Collector - Emitter Breakdown Voltage	BV _{CES}	$I_{C} = 10 \mu A, V_{GE} = 0 V$	650	ı	-	>
Collector Cut - off Current	I _{CES}	$V_{CE} = 650V, V_{GE} = 0V$	-	-	10	μΑ
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 30V$, $V_{CE} = 0V$	-	ı	±200	nA
Gate - Emitter Threshold Voltage	$V_{GE(th)}$	$V_{CE} = 5V, I_{C} = 34.3 \text{mA}$	5.0	6.0	7.0	V
		$I_C = 50A, V_{GE} = 15V,$				
Collector - Emitter Saturation Voltage	V _{CE(sat)} *3	T _j = 25°C	-	1.5	1.9	V
Voltago		T _j = 175°C	-	1.85	-	
Input Capacitance	C _{ies}	V _{CE} = 30V,	-	2890	-	
Output Capacitance	C _{oes}	$V_{GE} = 0V$,	-	116	-	pF
Reverse transfer Capacitance	C _{res}	f = 1MHz	-	48	-	
Total Gate Charge	Q_g	V _{CE} = 400V,	-	104	-	
Gate - Emitter Charge	Q_ge	I _C = 50A,	-	21	-	nC
Gate - Collector Charge		V _{GE} = 15V	-	37	-	

^{*3} Design assurance without measurement

●Chip Information



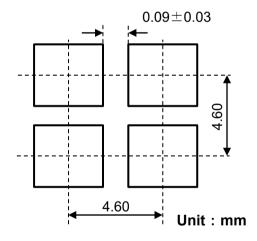
Unit: µm

Pad Area

1 : Gate Bonding Pad

② : Emitter Bonding Pad

Backside: Collector



Wafer Size	150mm		
Wafer Thickness	0.07±0.01mm		
Chip Size	4.60mm×4.60mm		
Cut Line Width	0.09±0.03mm		
Top Side Metallization	AlSiCu:4.4µm		
Back Side Metallization	Ti/Ni:0.4µm/Au:0.05µm		
Passivation	Polyimide		

•Further Electrical Characteristics

Switching characteristics and thermal properties are depending strongly on module design and mounting technology and can therefore not be specified for a bare die.

This chip data sheet refers to the device data sheet	RGTV00TS65

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